

Low-Voltage CMOS Octal Buffer Flow Through Pinout With 5V-Tolerant Inputs and Outputs (3-State, Inverting)

The MC74LCX540 is a high performance, inverting octal buffer operating from a 2.3 to 3.6V supply. This device is similar in function to the MC74LCX240, while providing flow through architecture. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5V allows MC74LCX540 inputs to be safely driven from 5V devices. The MC74LCX540 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

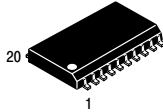
Current drive capability is 24mA at the outputs. The Output Enable ($\overline{OE1}$, $\overline{OE2}$) inputs, when HIGH, disables the outputs by placing them in a HIGH Z condition.

- Designed for 2.3 to 3.6V V_{CC} Operation
- 5V Tolerant — Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0V$
- LVTTTL Compatible
- LVC MOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 μ A)
Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

MC74LCX540

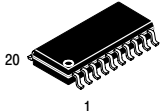
LCX

LOW-VOLTAGE CMOS OCTAL BUFFER



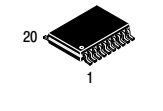
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DW SUFFIX
PLASTIC SOIC
CASE 751D-04



20
1

M SUFFIX
PLASTIC SOIC EIAJ
CASE 967-01



20
1

DT SUFFIX
PLASTIC TSSOP
CASE 948E-02

PIN NAMES

| Pins | Function |
|------------------|----------------------|
| $\overline{OE1}$ | Output Enable Inputs |
| Dn | Data Inputs |
| $\overline{O1}$ | 3-State Outputs |

MC74LCX540

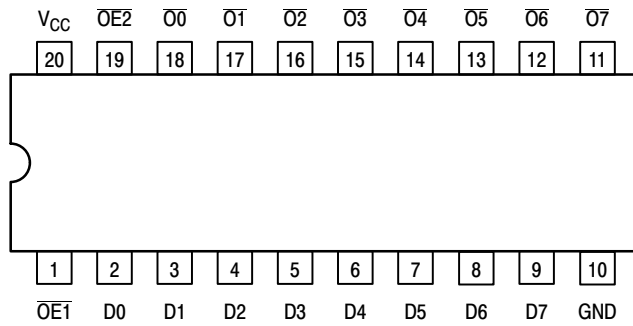


Figure 1. Pinout: 20-Lead (Top View)

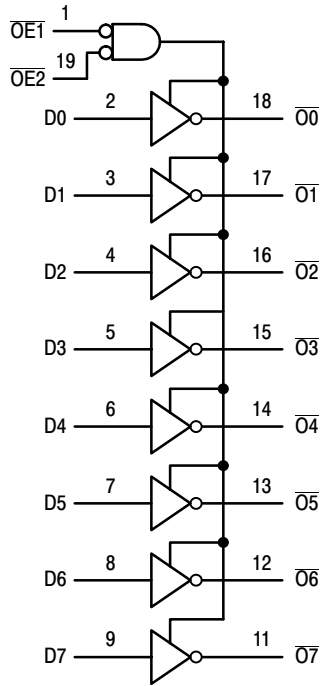


Figure 2. LOGIC DIAGRAM

| INPUTS | | | OUTPUTS |
|-----------------|-----------------|----------------|----------------|
| OE ₁ | OE ₂ | D _n | O _n |
| L | L | L | H |
| L | L | H | L |
| X | H | X | Z |
| H | X | X | Z |

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions Are Acceptable, for I_{CC} reasons, DO NOT FLOAT Inputs

MC74LCX540

ABSOLUTE MAXIMUM RATINGS*

| Symbol | Parameter | Value | Condition | Unit |
|------------------|----------------------------------|---|----------------------------------|------|
| V _{CC} | DC Supply Voltage | -0.5 to +7.0 | | V |
| V _I | DC Input Voltage | -0.5 ≤ V _I ≤ +7.0 | | V |
| V _O | DC Output Voltage | -0.5 ≤ V _O ≤ +7.0 | Output in 3-State | V |
| | | -0.5 ≤ V _O ≤ V _{CC} + 0.5 | Note 1. | V |
| I _{IK} | DC Input Diode Current | -50 | V _I < GND | mA |
| I _{OK} | DC Output Diode Current | -50 | V _O < GND | mA |
| | | +50 | V _O > V _{CC} | mA |
| I _O | DC Output Source/Sink Current | ±50 | | mA |
| I _{CC} | DC Supply Current Per Supply Pin | ±100 | | mA |
| I _{GND} | DC Ground Current Per Ground Pin | ±100 | | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | | °C |

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

1. Output in HIGH or LOW State. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Typ | Max | Unit | |
|-----------------|---|---------------------|-----|-----------------|------|---|
| V _{CC} | Supply Voltage | Operating | 2.0 | 3.3 | 3.6 | V |
| | | Data Retention Only | 1.5 | 3.3 | 3.6 | |
| V _I | Input Voltage | 0 | | 5.5 | V | |
| V _O | Output Voltage (HIGH or LOW State) (3-State) | 0 | | V _{CC} | V | |
| | | 0 | | 5.5 | | |
| I _{OH} | HIGH Level Output Current, V _{CC} = 3.0V – 3.6V | | | -24 | mA | |
| I _{OL} | LOW Level Output Current, V _{CC} = 3.0V – 3.6V | | | 24 | mA | |
| I _{OH} | HIGH Level Output Current, V _{CC} = 2.7V – 3.0V | | | -12 | mA | |
| I _{OL} | LOW Level Output Current, V _{CC} = 2.7V – 3.0V | | | 12 | mA | |
| T _A | Operating Free-Air Temperature | -40 | | +85 | °C | |
| Δt/ΔV | Input Transition Rise or Fall Rate, V _{IN} from 0.8V to 2.0V, V _{CC} = 3.0V | 0 | | 10 | ns/V | |

DC ELECTRICAL CHARACTERISTICS

| Symbol | Characteristic | Condition | T _A = -40°C to +85°C | | Unit |
|-----------------|------------------------------------|---|---------------------------------|------|------|
| | | | Min | Max | |
| V _{IH} | HIGH Level Input Voltage (Note 2.) | 2.7V ≤ V _{CC} ≤ 3.6V | 2.0 | | V |
| V _{IL} | LOW Level Input Voltage (Note 2.) | 2.7V ≤ V _{CC} ≤ 3.6V | | 0.8 | V |
| V _{OH} | HIGH Level Output Voltage | 2.7V ≤ V _{CC} ≤ 3.6V; I _{OH} = -100μA | V _{CC} - 0.2 | | V |
| | | V _{CC} = 2.7V; I _{OH} = -12mA | 2.2 | | |
| | | V _{CC} = 3.0V; I _{OH} = -18mA | 2.4 | | |
| | | V _{CC} = 3.0V; I _{OH} = -24mA | 2.2 | | |
| V _{OL} | LOW Level Output Voltage | 2.7V ≤ V _{CC} ≤ 3.6V; I _{OL} = 100μA | | 0.2 | V |
| | | V _{CC} = 2.7V; I _{OL} = 12mA | | 0.4 | |
| | | V _{CC} = 3.0V; I _{OL} = 16mA | | 0.4 | |
| | | V _{CC} = 3.0V; I _{OL} = 24mA | | 0.55 | |

2. These values of V_I are used to test DC electrical characteristics only.

MC74LCX540

DC ELECTRICAL CHARACTERISTICS (continued)

| Symbol | Characteristic | Condition | T _A = -40°C to +85°C | | Unit |
|------------------|---------------------------------------|--|---------------------------------|------|------|
| | | | Min | Max | |
| I _I | Input Leakage Current | 2.7V ≤ V _{CC} ≤ 3.6V; 0V ≤ V _I ≤ 5.5V | | ±5.0 | μA |
| I _{OZ} | 3-State Output Current | 2.7 ≤ V _{CC} ≤ 3.6V; 0V ≤ V _O ≤ 5.5V; V _I = V _{IH} or V _{IL} | | ±5.0 | μA |
| I _{OFF} | Power-Off Leakage Current | V _{CC} = 0V; V _I or V _O = 5.5V | | 10 | μA |
| I _{CC} | Quiescent Supply Current | 2.7 ≤ V _{CC} ≤ 3.6V; V _I = GND or V _{CC} | | 10 | μA |
| | | 2.7 ≤ V _{CC} ≤ 3.6V; 3.6 ≤ V _I or V _O ≤ 5.5V | | ±10 | μA |
| ΔI _{CC} | Increase in I _{CC} per Input | 2.7 ≤ V _{CC} ≤ 3.6V; V _{IH} = V _{CC} - 0.6V | | 500 | μA |

AC CHARACTERISTICS (t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500Ω)

| Symbol | Parameter | Waveform | Limits | | | Unit |
|--|--|----------|---------------------------------|------------|------------------------|------|
| | | | T _A = -40°C to +85°C | | | |
| | | | V _{CC} = 3.0V to 3.6V | | V _{CC} = 2.7V | |
| | | | Min | Max | Max | |
| t _{PLH} t _{PHL} | Propagation Delay Input to Output | 1 | 1.5 1.5 | 6.5 6.5 | 7.5 7.5 | ns |
| t _{PZH} t _{PZL} | Output Enable Time to High and Low Level | 2 | 1.5 1.5 | 8.5 8.5 | 9.5 9.5 | ns |
| t _{PHZ} t _{PLZ} | Output Disable Time From High and Low Level | 2 | 1.5 1.5 | 7.5 7.5 | 8.5 8.5 | ns |
| t _{OSSL} t _{OSLH} | Output-to-Output Skew (Note 3.) | | | 1.0 1.0 | | ns |

3. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSSL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

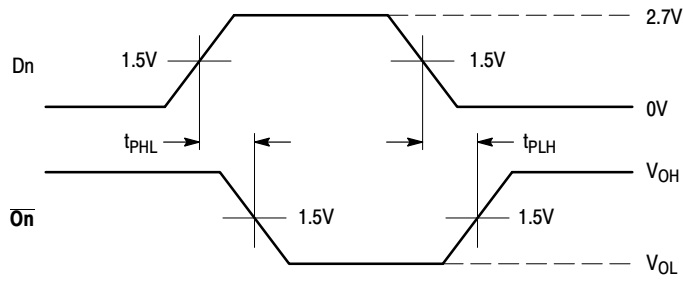
| Symbol | Characteristic | Condition | T _A = +25°C | | | Unit |
|------------------|--------------------------------------|---|------------------------|-----|-----|------|
| | | | Min | Typ | Max | |
| V _{OLP} | Dynamic LOW Peak Voltage (Note 4.) | V _{CC} = 3.3V, C _L = 50pF, V _{IH} = 3.3V, V _{IL} = 0V | | 0.8 | | V |
| V _{OLV} | Dynamic LOW Valley Voltage (Note 4.) | V _{CC} = 3.3V, C _L = 50pF, V _{IH} = 3.3V, V _{IL} = 0V | | 0.8 | | V |

4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

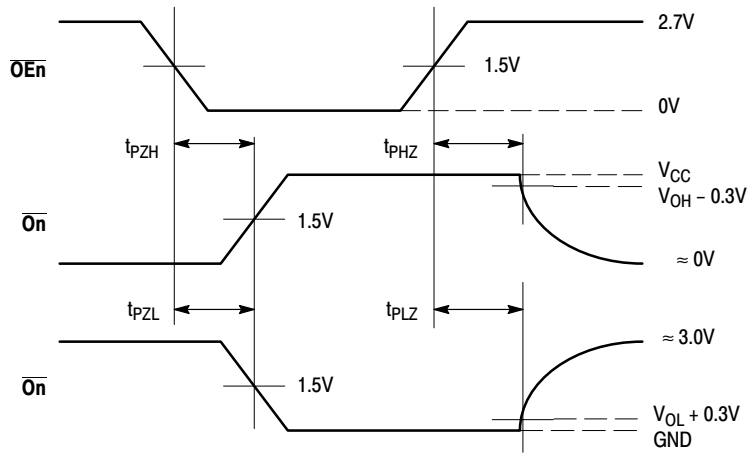
CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Condition | Typical | Unit |
|------------------|-------------------------------|---|---------|------|
| C _{IN} | Input Capacitance | V _{CC} = 3.3V, V _I = 0V or V _{CC} | 7 | pF |
| C _{OUT} | Output Capacitance | V _{CC} = 3.3V, V _I = 0V or V _{CC} | 8 | pF |
| C _{PD} | Power Dissipation Capacitance | 10MHz, V _{CC} = 3.3V, V _I = 0V or V _{CC} | 25 | pF |

MC74LCX540

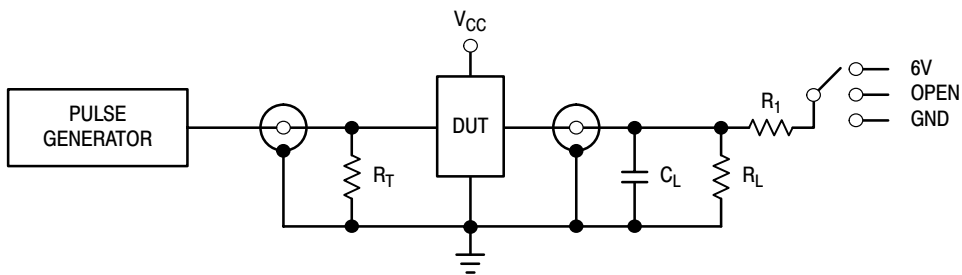


WAVEFORM 1 - PROPAGATION DELAYS
 $t_R = t_F = 2.5\text{ns}$, 10% to 90%; $f = 1\text{MHz}$; $t_W = 500\text{ns}$



WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES
 $t_R = t_F = 2.5\text{ns}$, 10% to 90%; $f = 1\text{MHz}$; $t_W = 500\text{ns}$

Figure 3. AC Waveforms



| TEST | SWITCH |
|--|--------|
| t_{PLH} , t_{PHL} | Open |
| t_{PZL} , t_{PLZ} | 6V |
| Open Collector/Drain t_{PLH} and t_{PHL} | 6V |
| t_{PZH} , t_{PHZ} | GND |

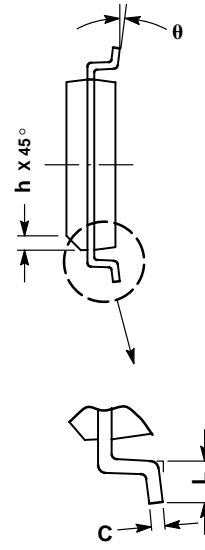
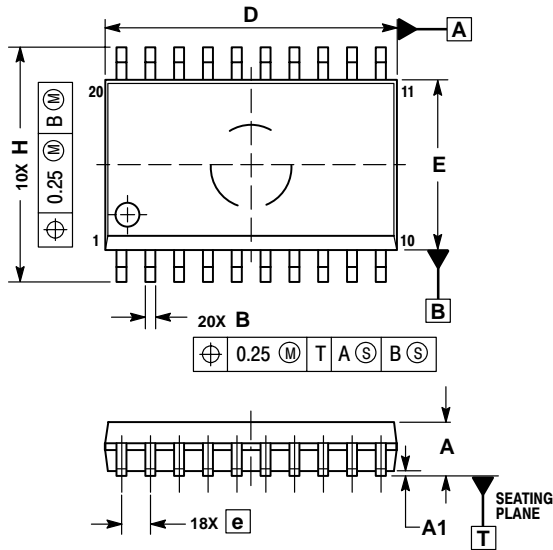
$C_L = 50\text{pF}$ or equivalent (Includes jig and probe capacitance)
 $R_L = R_1 = 500\Omega$ or equivalent
 $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Figure 4. Test Circuit

MC74LCX540

OUTLINE DIMENSIONS

DW SUFFIX PLASTIC SOIC PACKAGE CASE 751D-04 ISSUE E

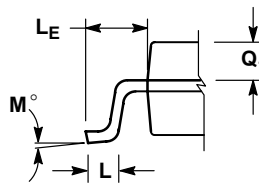
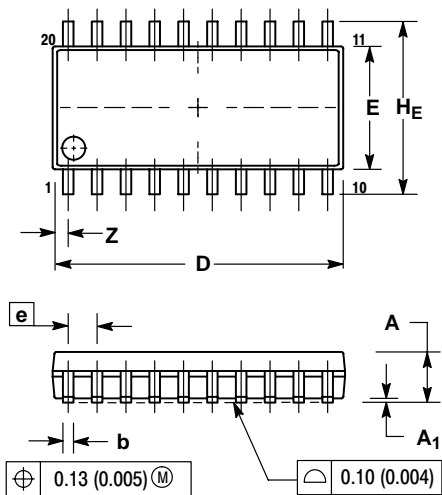


NOTES:

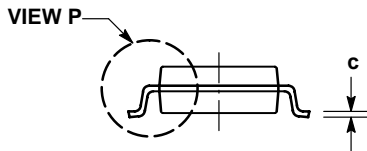
- DIMENSIONS ARE IN MILLIMETERS.
- INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | |
|-------|-------------|-------|
| | MIN | MAX |
| A | 2.35 | 2.65 |
| A1 | 0.10 | 0.25 |
| B | 0.35 | 0.49 |
| C | 0.23 | 0.32 |
| D | 12.65 | 12.95 |
| E | 7.40 | 7.60 |
| e | 1.27 BSC | |
| H | 10.05 | 10.55 |
| h | 0.25 | 0.75 |
| L | 0.50 | 0.90 |
| theta | 0° | 7° |

M SUFFIX PLASTIC SOIC EIAJ PACKAGE CASE 967-01 ISSUE O



DETAIL P



NOTES:

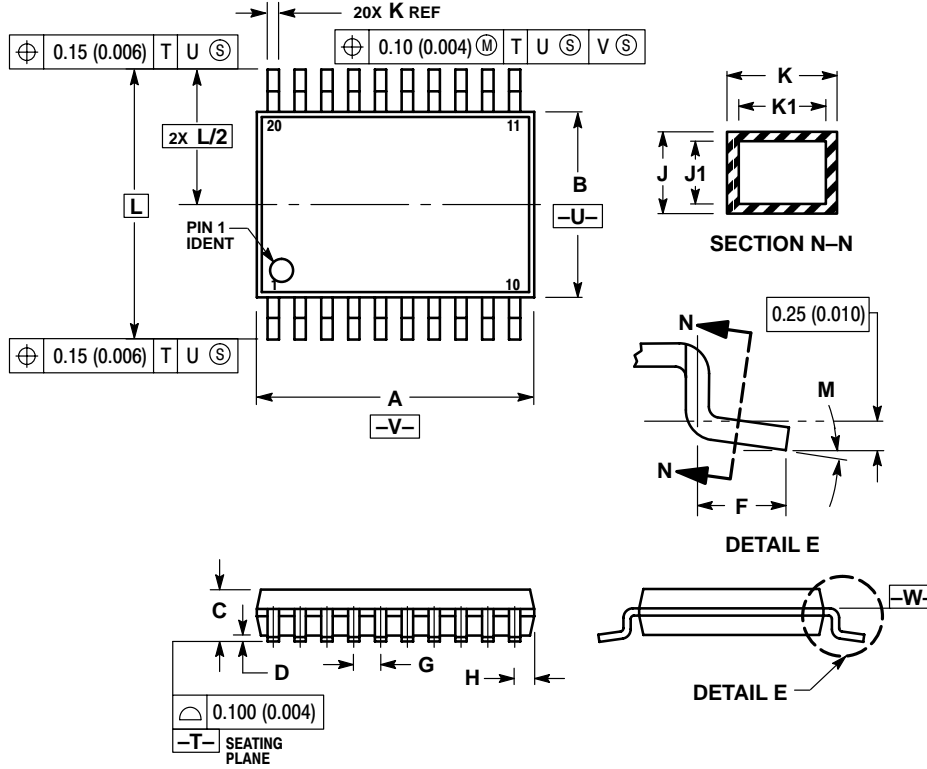
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | --- | 2.05 | --- | 0.081 |
| A1 | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| c | 0.18 | 0.27 | 0.007 | 0.011 |
| D | 12.35 | 12.80 | 0.486 | 0.504 |
| E | 5.10 | 5.45 | 0.201 | 0.215 |
| e | 1.27 BSC | | 0.050 BSC | |
| H_E | 7.40 | 8.20 | 0.291 | 0.323 |
| L | 0.50 | 0.85 | 0.020 | 0.033 |
| L_E | 1.10 | 1.50 | 0.043 | 0.059 |
| M | 0° | 10° | 0° | 10° |
| Q_1 | 0.70 | 0.90 | 0.028 | 0.035 |
| Z | --- | 0.81 | --- | 0.032 |

MC74LCX540

OUTLINE DIMENSIONS


DT SUFFIX
 PLASTIC TSSOP PACKAGE
 CASE 948E-02
 ISSUE A



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 6.40 | 6.60 | 0.252 | 0.260 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | --- | 1.20 | --- | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC | | 0.026 BSC | |
| H | 0.27 | 0.37 | 0.011 | 0.015 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | | 0.252 BSC | |
| M | 0° | 8° | 0° | 8° |

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